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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/079,269	02/19/2002	Stewart Edward Hooper	YAMAP0800US	6114
75	90 06/06/2003			
Neil A. DuChez			EXAMINER	
19th Floor	oisselle & Sklar		KUNEMUND, ROBERT M	
1621 Euclid Av Cleveland, OH			ART UNIT	PAPER NUMBER
			1765	1
			DATE MAILED: 06/06/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

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.•				ication N .	Applicant(s)	
•	Offic	Action Cummen.	10/0	79,269	HOOPER ET	AL.
	Onic	Action Summary	Exan	niner	Art Unit	
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Period f		NG DATE of this commu	nication appears o	n the cover sh	eet with the correspondence	address
THE M - Extens after S - If the p - If NO p - Failure - Any re	IAILING DA sions of time ma IX (6) MONTH: period for reply period for reply to reply within ply received by	is specified above, the maximum s the set or extended period for rep	NICATION. as of 37 CFR 1.136(a). In munication. (30) days, a reply within the statutory period will apply by will, by statute, cause the	no event, however, ne statutory minimum and will expire SIX (the application to become	,	nis communication.
1) 🔲	Responsiv	ve to communication(s) f	filed on			
2a) <u></u> □	This action	n is FINAL.	2b)⊠ This action	on is non-final.		
3) Disp sitio	closed in a	accordance with the prac	on for allowance ex ctice under <i>Ex par</i>	ccept for forma te Quayle, 193	al matters, prosecution as to 35 C.D. 11, 453 O.G. 213.	o the merits is
4) 🛛 (Claim(s) 1	-19 is/are pending in the	application.			
4	a) Of the a	bove claim(s) is/a	are withdrawn from	n consideration	1.	
		is/are allowed.				
6)⊠ (Claim(s) <u>1-</u>	19 is/are rejected.				
		is/are objected to.				
		are subject to restri	iction and/or electi	on requiremen	t.	
Applicatio		· •		•		
9)[] T	he specific	ation is objected to by th	ne Examiner.			
10)[] Ti	he drawing	(s) filed on is/are	: a)☐ accepted or	b) objected to	by the Examiner.	
	Applicant n	nay not request that any ob	ojection to the drawi	ng(s) be held in	abeyance. See 37 CFR 1.85(a).
11) 🗌 Ti	he propose	ed drawing correction file	ed on is: a)[approved b	disapproved by the Exar	niner.
		, corrected drawings are re				
12)∐ TI	he oath or	declaration is objected to	o by the Examiner			
Priority un	nder 35 U.S	S.C. §§ 119 and 120				
13)🛛 A	\cknowledg	gment is made of a clain	n for foreign priorit	y under 35 U.S	S.C. § 119(a)-(d) or (f).	
a)⊠	All b)□	Some * c) ☐ None of:				
1	. Certif	fied copies of the priority	documents have	been received		
2	2.☐ Certif	fied copies of the priority	documents have	been received	in Application No	
	а	es of the certified copies pplication from the Inter thed detailed Office action	national Bureau (F	PCT Rule 17.2		nal Stage
14) <u></u> Ac	knowledgn	nent is made of a claim	for domestic priori	ly under 35 U.	S.C. § 119(e) (to a provisio	nal application).
a)	☐ The trai knowledgr	nslation of the foreign la	nguage provisiona	al application h		
1) Notice	of References of Draftsperso	s Cited (PTO-892) on's Patent Drawing Review (f re Statement(s) (PTO-1449) F			view Summary (PTO-413) Paper ce of Informal Patent Application (r:	
.S. Patent and Trad PTO-326 (Rev.	lemark Office 04-01)		Office Action Sur	nmary	Part of Paper No	o. 5

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DETAILED ACTION

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 14 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The claim does not distinctly point out and claim the instant invention. The claim refers to a third concentration of indium in claim 1. However, claim one does not recite three separate indium concentrations. Thus, it is unclear as to which concentration claim 14 refers to in claim 1.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to

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consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1, 4, 12, 13, and 16 to 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Udagawa (6,541,797).

The Udagawa reference teaches a process for the growth of GaInN layers where the concentration of the indium is varied between the layers. On a substrate, a first layer of gallium nitride is grown. Then a first layer of GaInN is deposited with a first concentration of indium. A second layer of GaInN is then deposited on top of the first layer with a second indium concentration. The first and second indium concentrations are different and the second concentration is greater then the first. The deposition technique is molecular beam epitaxy and the temperature of growth is above 650°c. The grown structure is used as a limit emitting device, note, entire reference and in particular the examples. The sole difference between the instant claims and the prior art is the varying of the indium source gas. However, in the absence of unexpected results, it would have been obvious to one of ordinary skill in the art to determine through routine experimentations the optimum, operable method of varying the indium concentration by varying the indium source gas in the Udagawa method in order to achieve the desired concentration and control over the concentration in each layer.

Claims 2, 3, 5 to 11, 14 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Udagawa (6,541,797).

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The Udagawa reference is relied on for the same reasons as stated, supra, and differs from the instant claims in the process parameters. However, in the absence of unexpected results, it would have been obvious to one of ordinary skill in the art to determine through routine experimentations the optimum, operable process parameters in the Udagawa method in order to grow layers with the high degree of quality needed to produce light emitting devices.

Examiner's Remarks

The remaining references are merely cited of interest as showing the state of the art.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Robert M Kunemund whose telephone number is 703-308-1091. The examiner can normally be reached on 8 hours.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Ben Utech can be reached on 703-308-3636. The fax phone numbers for the organization where this application or proceeding is assigned are 703-305-3599 for regular communications and 703-305-3599 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0651.

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May 30, 2003

ROBERT KUNEMUND